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Challenges and Status of the FCC-ee lattice design

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Future Circular Collider Study

- New 80-100 km storage ring
- **FCC-hh** (=long-term goal):
 - High-energy hadron collider
 - Push the energy frontier to 100 TeV

- **FCC-ee (TLEP):**
 - e^+/e^- -collider as intermediate step




- **FCC-he**
 - Hadron-lepton collider option
 - Deep inelastic scattering

Future Circular Collider Study
Kick-off Meeting

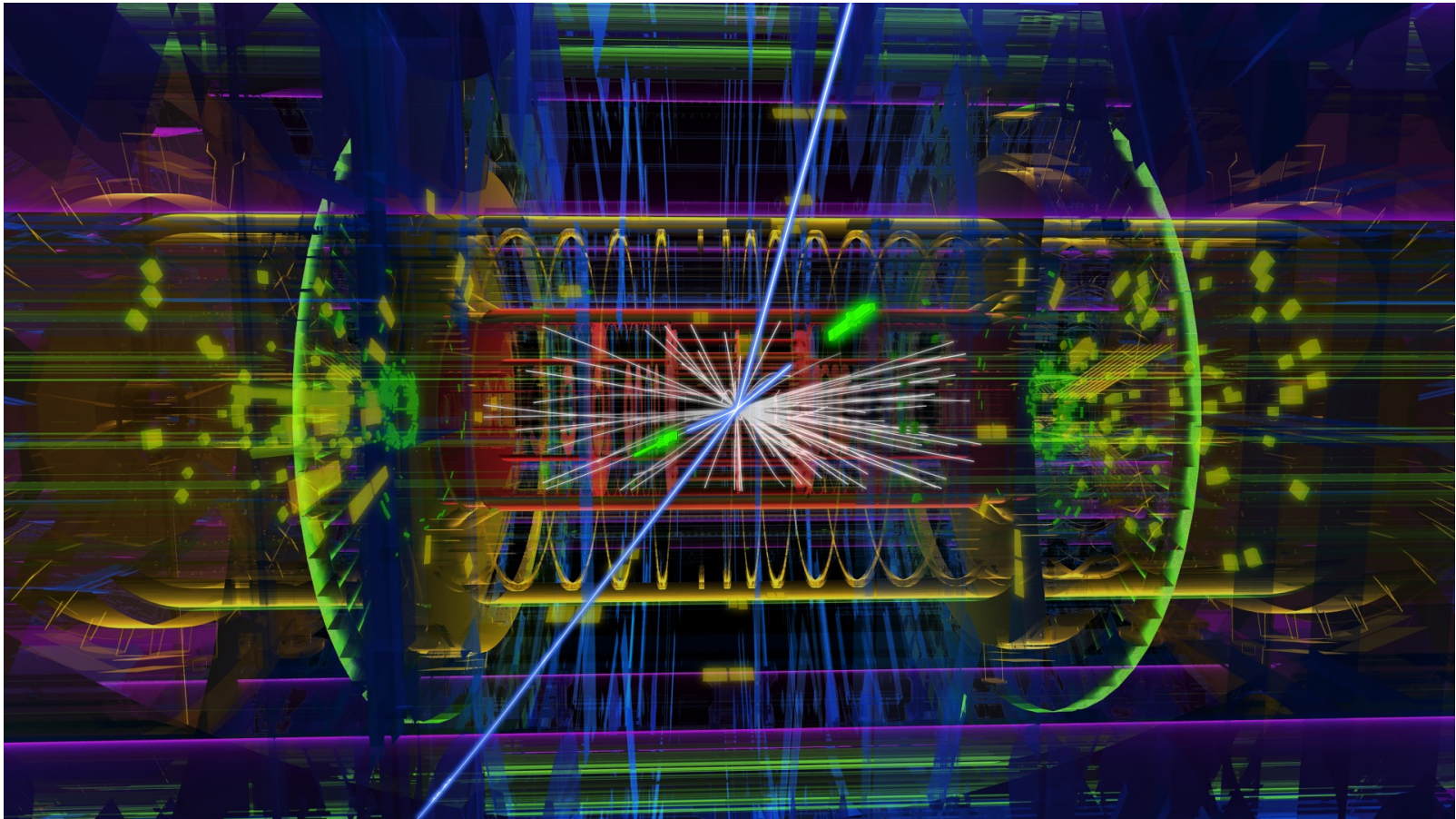
12-15 February 2014,
University of Geneva,
Switzerland

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C. Doglioni, G. Iacobucci,
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  UNIVERSITÉ DE GENÈVE  <http://indico.cern.ch/e/fcc-kickoff>

What is our goal?



- ATLAS event display: $H \rightarrow e^+ + e^- + \mu^+ + \mu^-$

Physics goals of FCC-ee

Provide highest possible luminosity for a wide physics program ranging from the Z pole to the tt production threshold.

- Beam energy range from 45 GeV to 175 GeV

Main physics programs / energies (+ scan around central values):

- Z (45.5 GeV): Z pole, high precision of M_Z and Γ_Z ,
- W (80 GeV): W pair production threshold,
- H (120 GeV): H production,
- T (175 GeV): tt threshold.

All energies quoted refer to BEAM energies

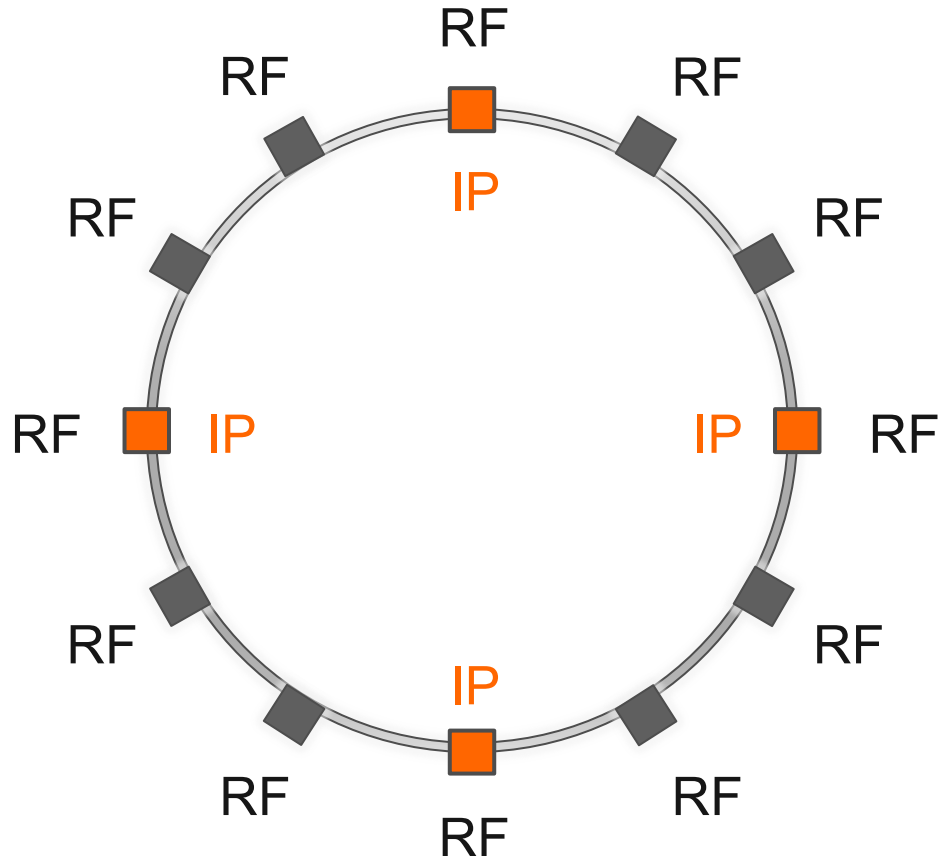
Main challenge: the parameter list

	Z	W	H	tt
Beam energy [GeV]	45.5	80	120	175
Beam current [mA]	1450	152	30	6.6
Bunches / beam	16700	4490	1330	160
Bunch population [10^{11}]	1.8	0.7	0.46	0.83
Transverse emittance ϵ				
- Horizontal [nm]	29.2	3.3	0.94	2
- Vertical [nm]	0.06	0.007	0.0019	0.002
Momentum comp. [10^{-5}]	18	2	0.5	0.5
Betatron function at IP β^*				
- Horizontal [mm]	500	500	500	1000
- Vertical [mm]	1	1	1	1
Energy loss / turn [GeV]	0.03	0.33	1.67	7.55
Total RF voltage [GV]	2.5	4	5.5	11

- Design & optimize a lattice for **4 different energies**
- Interaction region layout for a **large number of bunches**
- Horizontal emittance is **increasing** with reduced energy
- **Extremely small vert. beta*** ($\beta_y^* = 1 \text{ mm}$)
→ High chromaticity
→ Challenging dynamic aperture
- **High synchrotron radiation losses** include sophisticated absorber design in the lattice

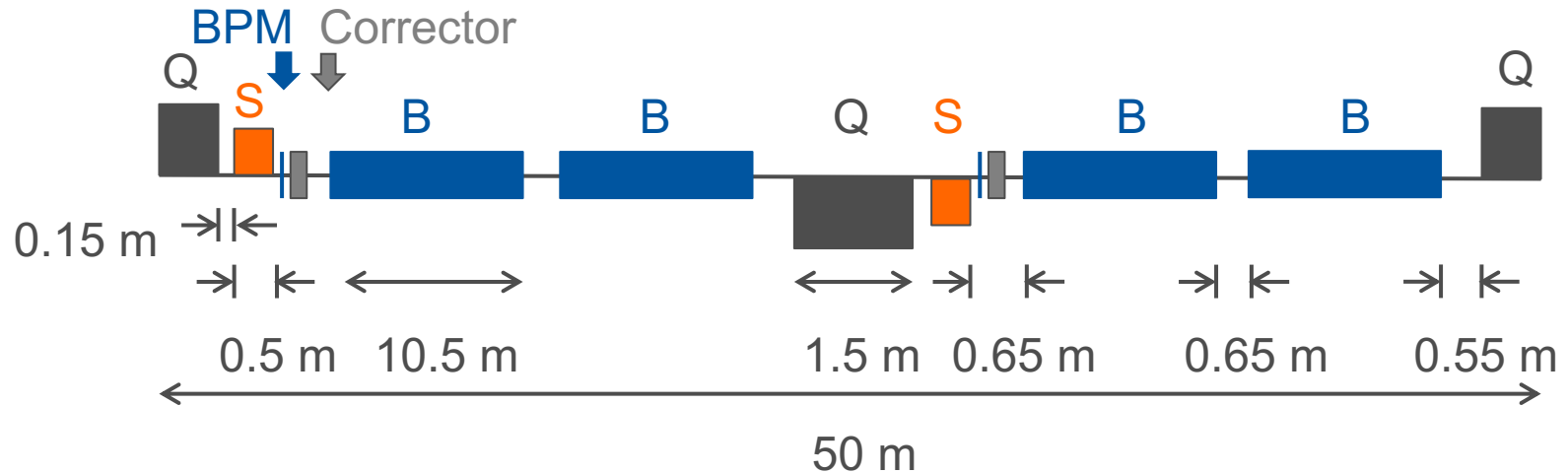
The FCC-ee Layout

- 100 km circumference
- 12 arcs (2 x 3.4 km)
- 12 long straight sections (1.5 km)
→ RF installations
- 4 mini-beta insertions
- 2 rings side-by-side



FODO cell for 175 GeV

Layout already considers max. dipole length, drift spaces for absorbers, flanges etc.



B = bending magnet, Q = quadrupole, S = sextupole

$N_{\text{dipoles}} = 6528$ (384 half bend) (LHC: 1232)

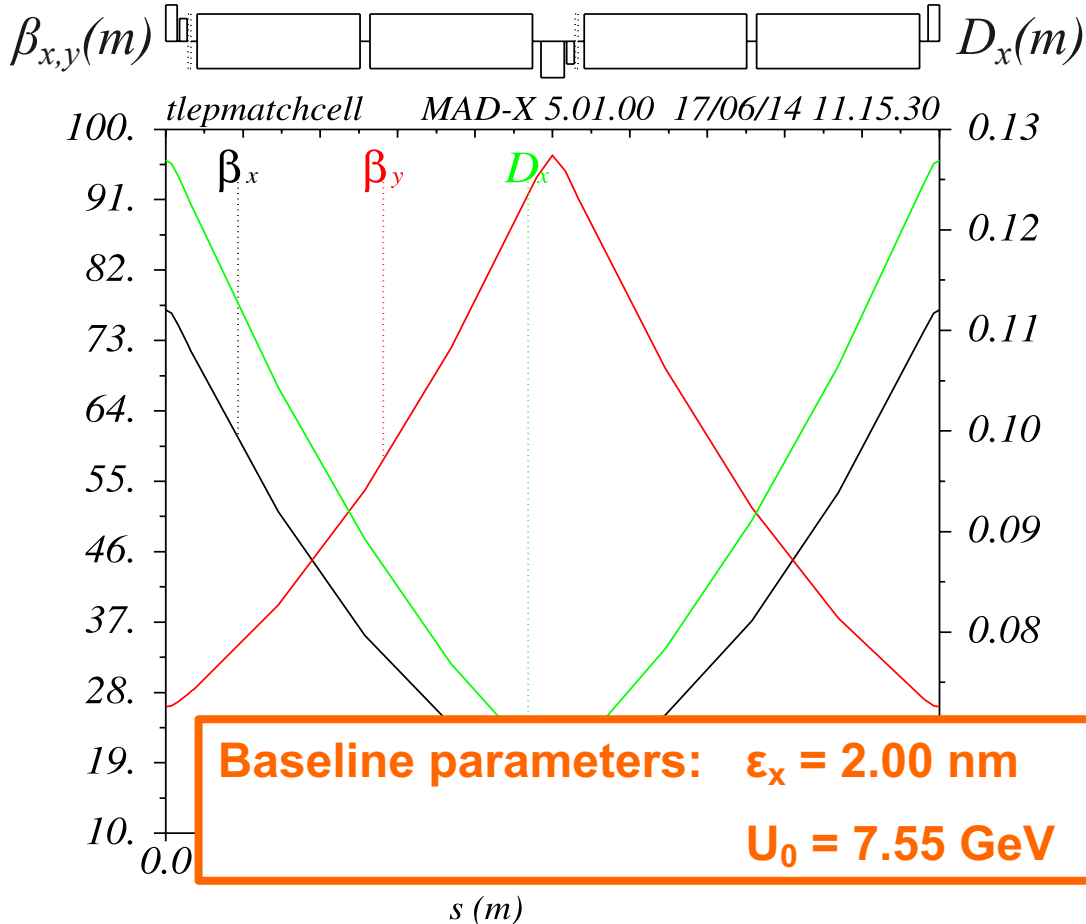
$N_{\text{quadrupoles}} = 4704$ (LHC: 478)

$\rho \approx 10.6$ km

$\theta = 0.99$ mrad

$B = 55$ mT

FODO cell for 175 GeV



- $L = 50$ m
- $\Psi = 90^\circ/60^\circ$
- $\beta_{x,\max} = 76.9$ m
- $\beta_{y,\max} = 96.6$ m
- $D_{x,\max} = 12.7$ cm

MADX Emit:

- $\epsilon_x = 1.00$ nm
- $U_0 = 7.72$ GeV

Emittance in electron storage rings



Fermilab

TM-1269
0102.000

Minimizing the Emittance in Designing the Lattice of an Electron Storage Ring

L.C. Teng

June 1984



$$\varepsilon_x = \frac{C_g}{J_x} \gamma^2 \theta^3 F$$

$$F_{FODO} = \frac{1}{2 \sin \psi} \frac{5 + 3 \cos \psi}{1 - \cos \psi} \frac{L}{l_B}$$

$C_g = 3.832 \times 10^{-13}$ m, J_x = damping partition number, γ = Lorentz factor,
 θ = bending angle, F = numerical factor controlled by the lattice design

Emittance in electron storage rings




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$$\epsilon_x = \frac{C_g}{J_x} \gamma^2 \theta^3 F$$

$$F_{FODO} = \frac{1}{2 \sin \psi} \frac{5 + 3 \cos \psi}{1 - \cos \psi} \frac{L}{l}$$

Analytic calculation:

$$\epsilon_x = 1.04 \text{ nm}$$

MADX Emit:

$$\epsilon_x = 1.00 \text{ nm}$$



120 GeV

$$\varepsilon_x = \frac{C_g}{J_x} \gamma^2 \theta^3 F$$

If the beam energy will be decreased from 175 GeV to 120 GeV the **beam emittance is expected to shrink!**

$$F(\Psi=90^\circ) = 2.976, \quad \gamma(175 \text{ GeV}) = 342466, \quad \gamma(120 \text{ GeV}) = 234834$$

- Analytic calculation: $\varepsilon_x = 0.491 \text{ nm}$
- MADX Emit: $\varepsilon_x = 0.488 \text{ nm}$ ✓
- Baseline parameter: $0.5 \times \varepsilon_x = 0.47 \text{ nm}$ ($\varepsilon_x = 0.94 \text{ nm}$)

We can keep the 175 GeV optics for 120 GeV beam energy!

45.5 GeV and 80.0 GeV

80.0 GeV: $\gamma = 156556$

- Baseline parameter: $0.5 \times \varepsilon_x = 1.65 \text{ nm}$ ($\varepsilon_x = 3.30 \text{ nm}$)
- Analytic calculation: $\varepsilon_x = 0.218 \text{ nm}$

45.5 GeV: $\gamma = 89041$

- Baseline parameter: $0.5 \times \varepsilon_x = 14.60 \text{ nm}$ ($\varepsilon_x = 29.20 \text{ nm}$)
- Analytic calculation: $\varepsilon_x = 0.071 \text{ nm}$

How can the beam emittance be increased?

$$\varepsilon_x = \frac{C_g}{J_x} \gamma^2 \theta^3 F$$

Changing the emittance for lower energies

$$\varepsilon = \left(\frac{\delta p}{p} \right)^2 (\gamma D^2 + 2\alpha D D' + \beta D'^2)$$
$$\hat{D} = \frac{L_{cell}^2}{\rho} \cdot \left(1 + \frac{1}{2} \sin^2 \left(\frac{\psi_{cell}}{2} \right) \right) / \sin^2 \left(\frac{\psi_{cell}}{2} \right)$$

There are two different possibilities:

1) Changing of the cell length

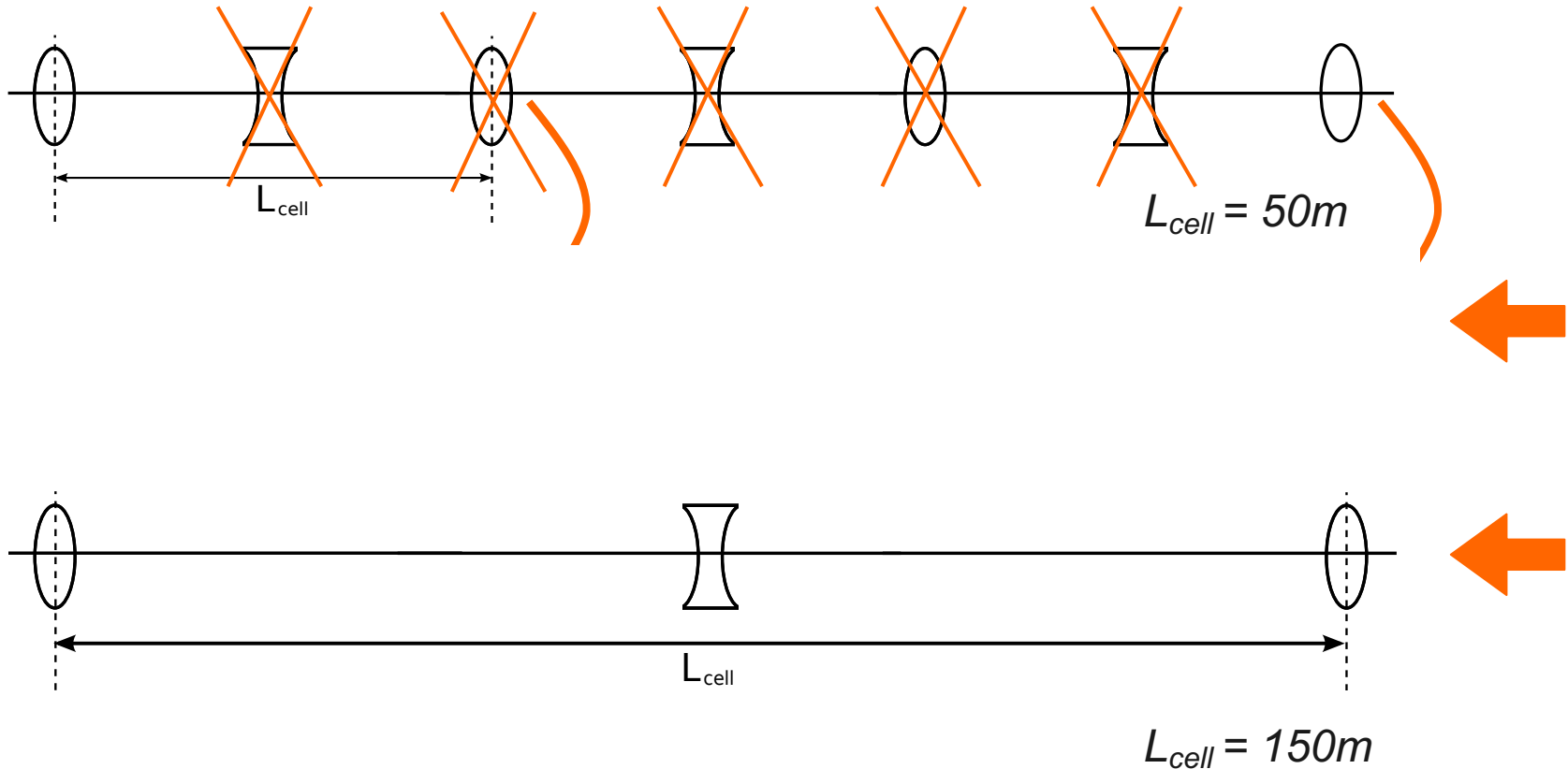
→ Larger emittance: **increase cell length**

→ $2 \times L_{cell}$, $3 \times L_{cell}$, $4 \times L_{cell}$, ...

- Recabeling of quadrupoles necessary

- Dispersion suppressors need to be adjusted

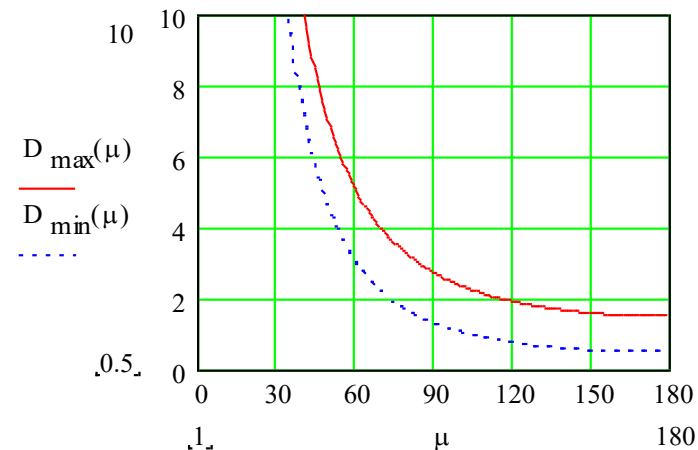
1) Changing of the cell length



Changing the emittance for lower energies

$$\varepsilon = \left(\frac{\delta p}{p} \right)^2 (\gamma D^2 + 2\alpha D D' + \beta D'^2)$$

$$\hat{D} = \frac{L_{cell}^2}{\rho} \cdot \left(1 + \frac{1}{2} \sin\left(\frac{\psi_{cell}}{2}\right) \right) / \sin^2\left(\frac{\psi_{cell}}{2}\right)$$



Court. B. Holzer

There are two different possibilities:

2) Change the phase advance Ψ of the FODO cell

- + No recabeling of hardware necessary
- Dispersion suppressors need to be adjusted
- Sextupole scheme? $\rightarrow 45^\circ, 60^\circ, 72^\circ, 90^\circ, \dots$
- Only within certain limits possible: $40^\circ < \Psi < 135^\circ$

Feasible Lattice Changes

80 GeV beam energy:

Cell length L	Phase advance Ψ	Emittance ϵ_x
Baseline parameter:	$2 \times$	1.65 nm
50 m	45°	1.50 nm (Teng)
100 m	90°	1.74 nm (Teng)

45.5 GeV beam energy:

Cell length L	Phase advance Ψ	Emittance ϵ_x
Baseline parameter:	$2 \times$	14.60 nm
200 m	60°	13.56 nm (Teng)
250 m	72°	15.91 nm (Teng)
300 m	90°	15.24 nm (Teng)

Objectives

- Introduce dispersion suppressors based on quadrupoles
 - Geometry must stay the same
- Beta functions in dispersion suppressor and matching sections should stay in the same order of magnitude as in the arcs
- Keep straight sections the same
 - Space is limited
 - No change of optics for injection, IR, etc. necessary

Lattices for 80 GeV

175 GeV and 120 GeV: $L_{\text{cell}} = 50 \text{ m}$, $\Psi = 90^\circ/60^\circ$



80 GeV: $L_{\text{cell}} = 50 \text{ m}$, $\Psi = 45^\circ/45^\circ$

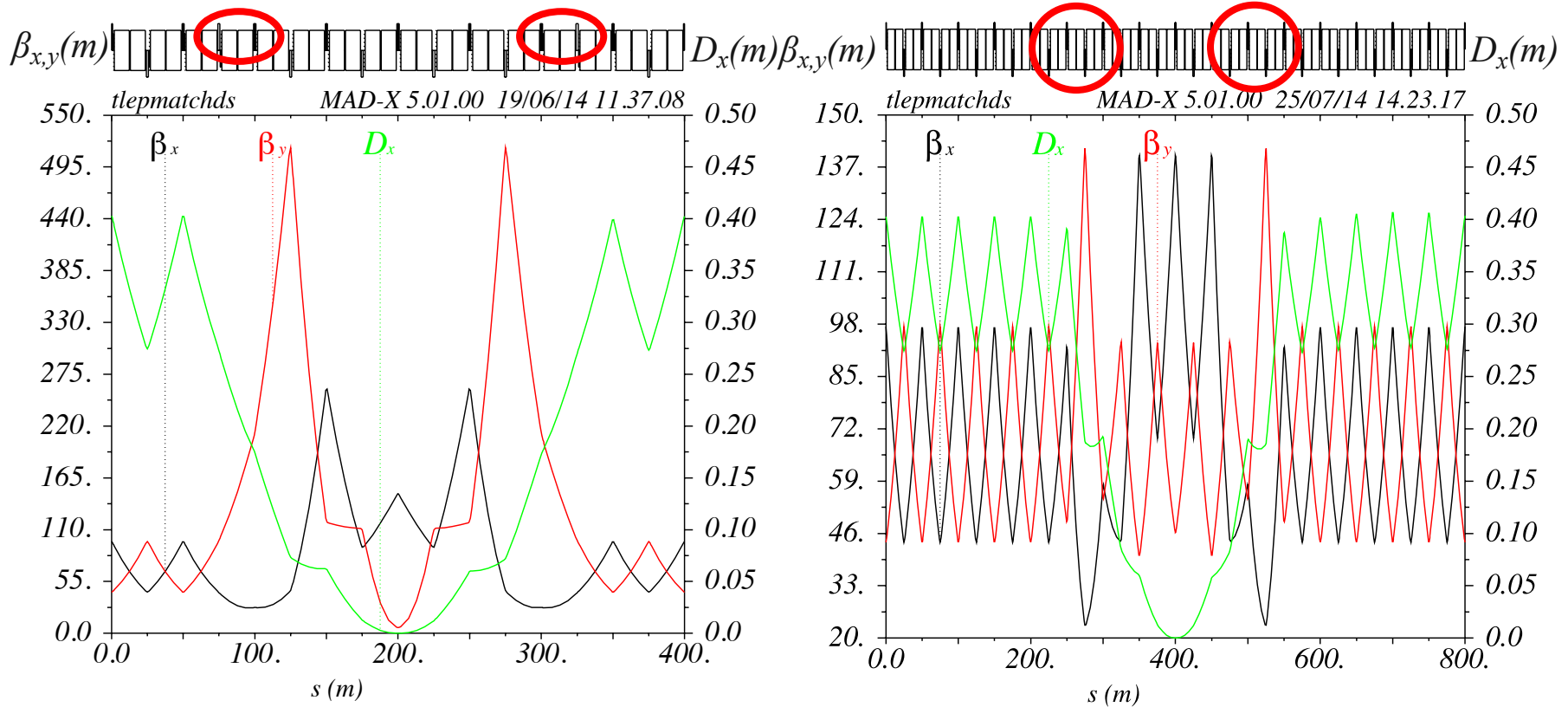


80 GeV: $L_{\text{cell}} = 100 \text{ m}$, $\Psi = 90^\circ/60^\circ$



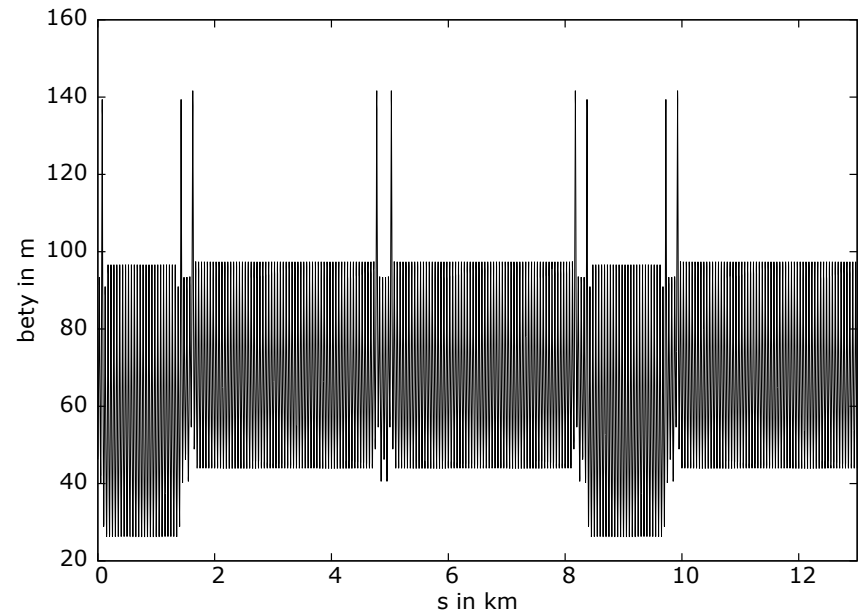
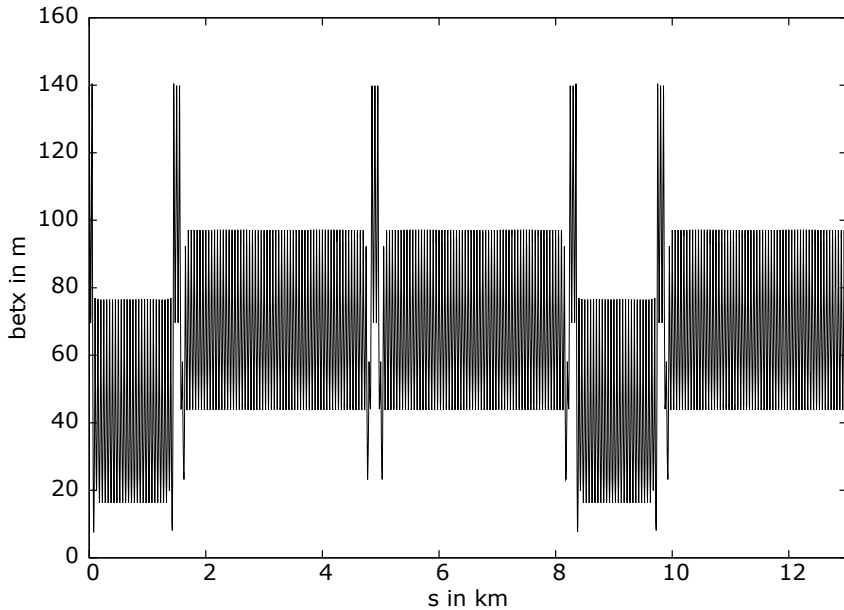
- | | |
|-------------------------|---------------------------------------|
| ■ Arc cells | ■ Straight matching section (with RF) |
| ■ Dispersion Suppressor | ■ Straight cells (with RF) |

80 GeV: 1) $\Psi=45^\circ$



Using 4 additional quadrupoles instead of 2 reduces the betafunction in the dispersion suppressor.

80 GeV: 1) $\Psi=45^\circ$



FCC-ee baseline parameter:

$$0.5 \times \epsilon_x = 1.65 \text{ nm}$$

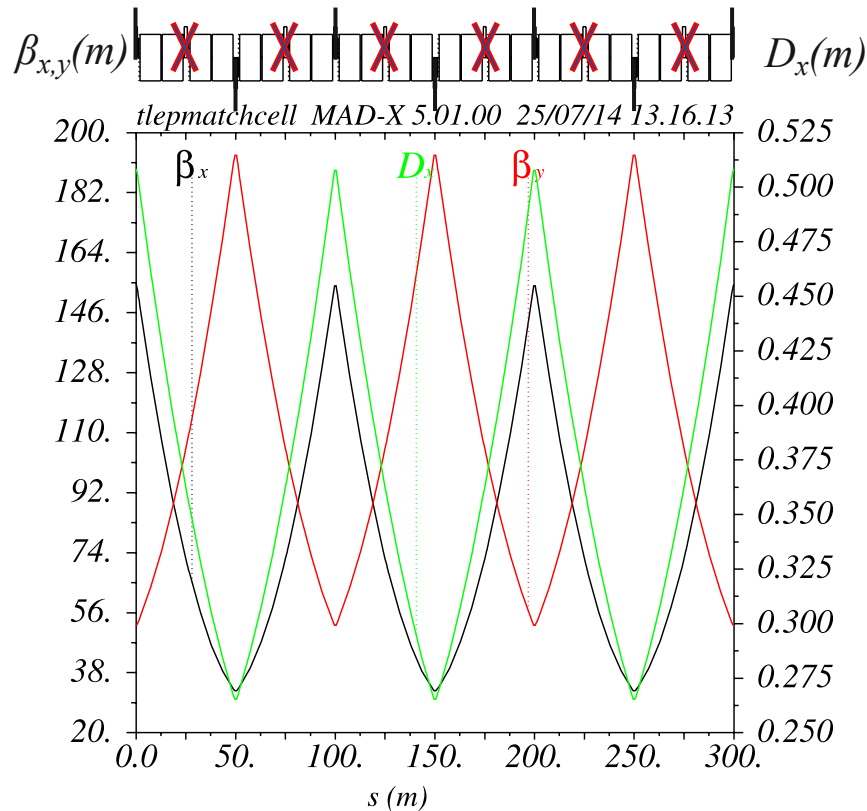
Analytical calculation:

$$\epsilon_x = 1.50 \text{ nm}$$

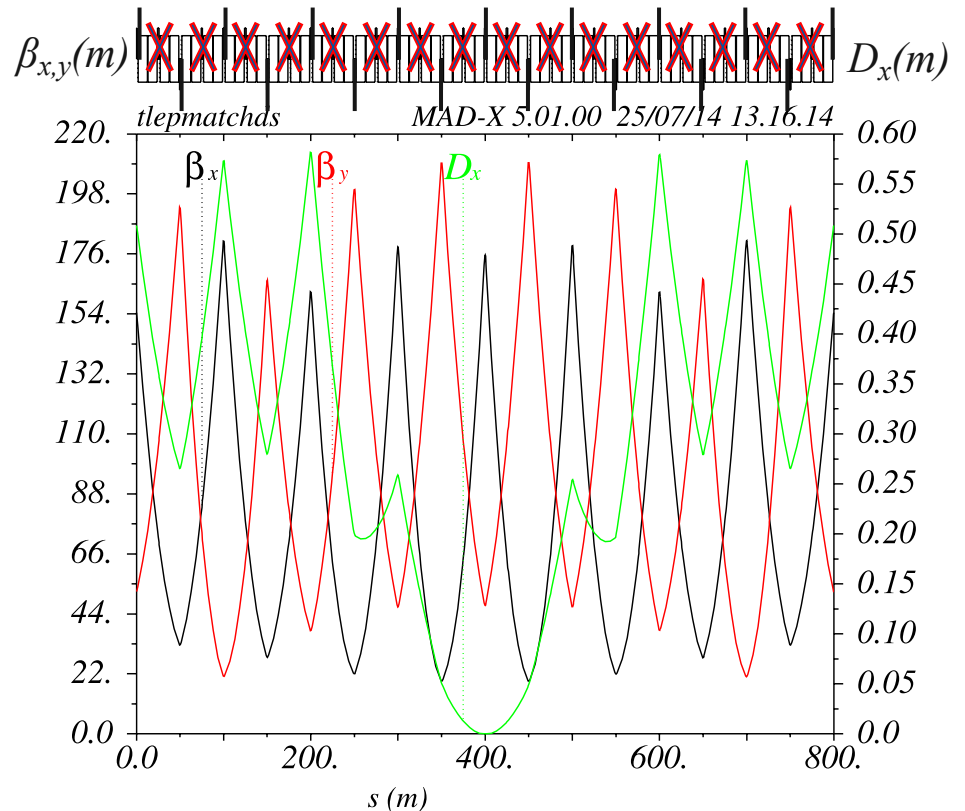
MADX Emit:

$$\epsilon_x = 1.47 \text{ nm}$$

80 GeV: 2) 100 m cell length

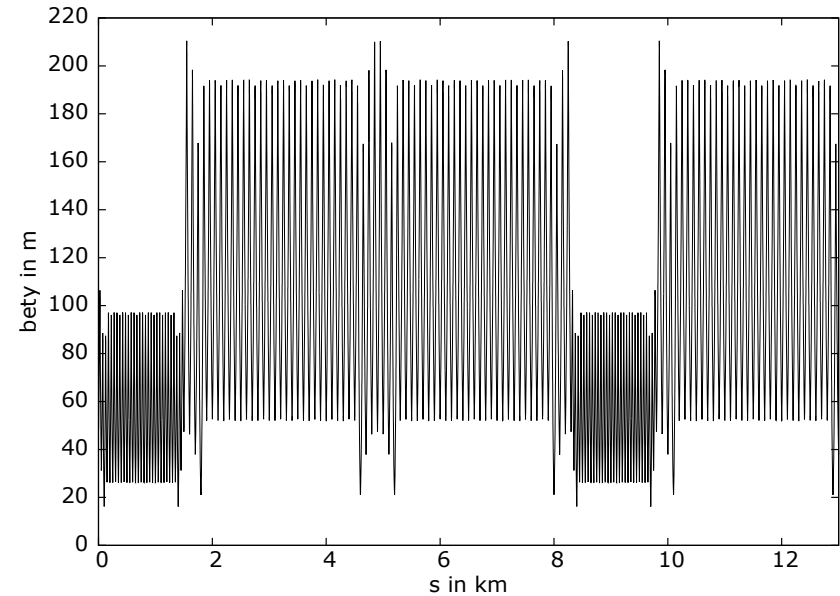
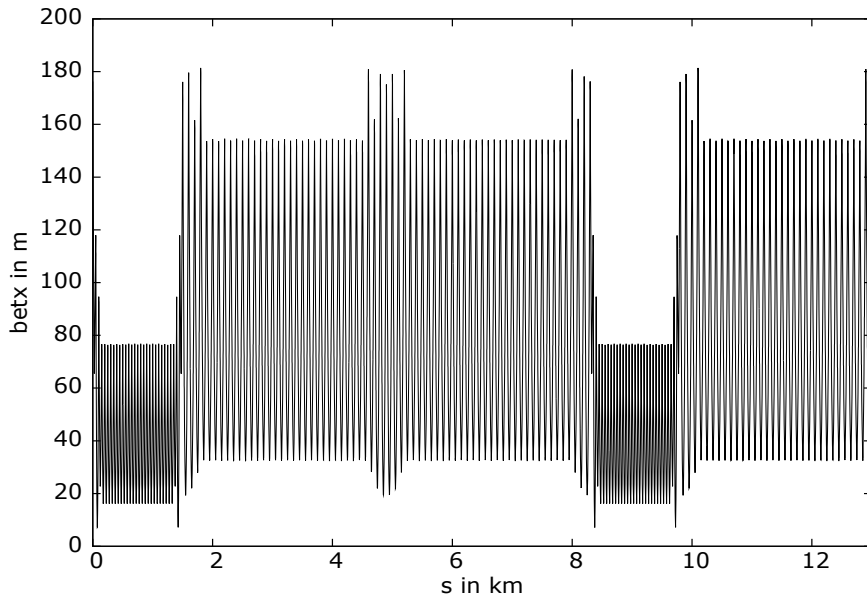


3 FODO cells



Dispersion suppressor

80 GeV: 2) 100 m cell length



FCC-ee baseline parameter:

Analytical calculation:

MADX Emit:

$0.5 \times \epsilon_x = 1.65 \text{ nm}$

$\epsilon_x = 1.74 \text{ nm}$

$\epsilon_x = 1.70 \text{ nm}$

Lattices for 45.5 GeV

175 GeV and 120 GeV: $L_{\text{cell}} = 50 \text{ m}$, $\Psi = 90^\circ/60^\circ$



45.5 GeV: $L_{\text{cell}} = 200 \text{ m}$, $\Psi = 60^\circ/60^\circ$



Dispersion suppressor based on quadrupoles

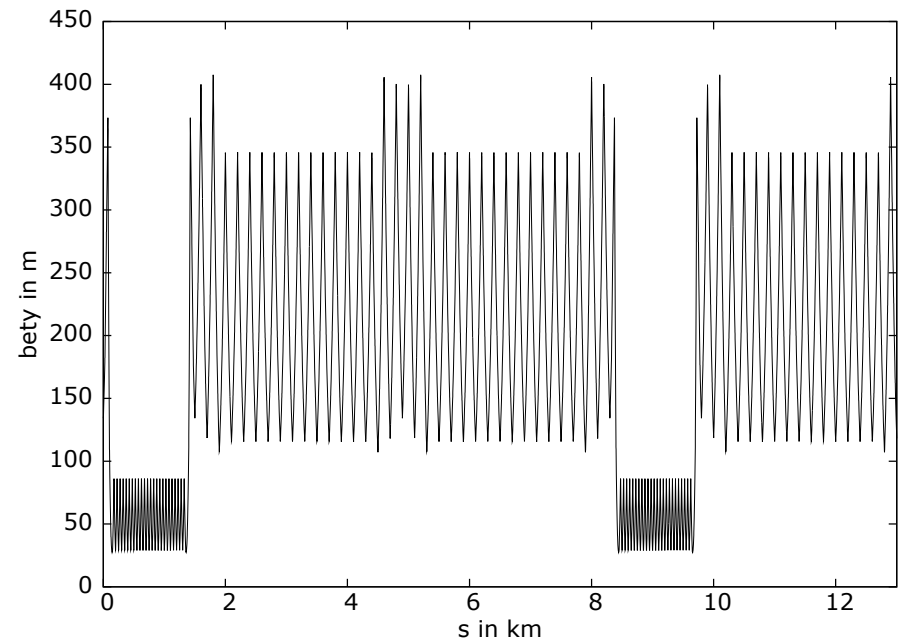
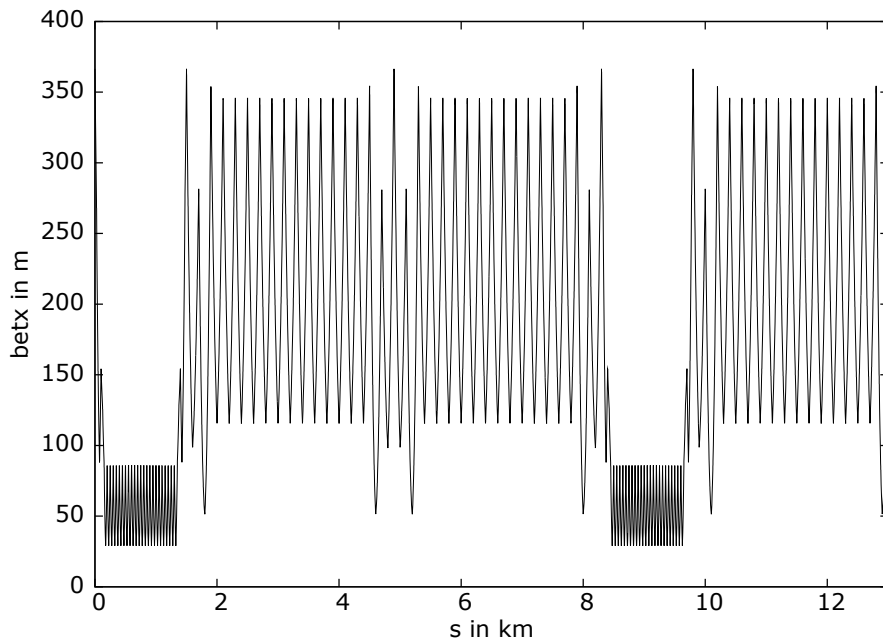
45.5 GeV: $L_{\text{cell}} = 250 \text{ m}$, $\Psi = 72^\circ/72^\circ$



45.5 GeV: $L_{\text{cell}} = 300 \text{ m}$, $\Psi = 90^\circ/60^\circ$



45.5 GeV: 200 m cell length



FCC-ee baseline parameter:

Analytical calculation:

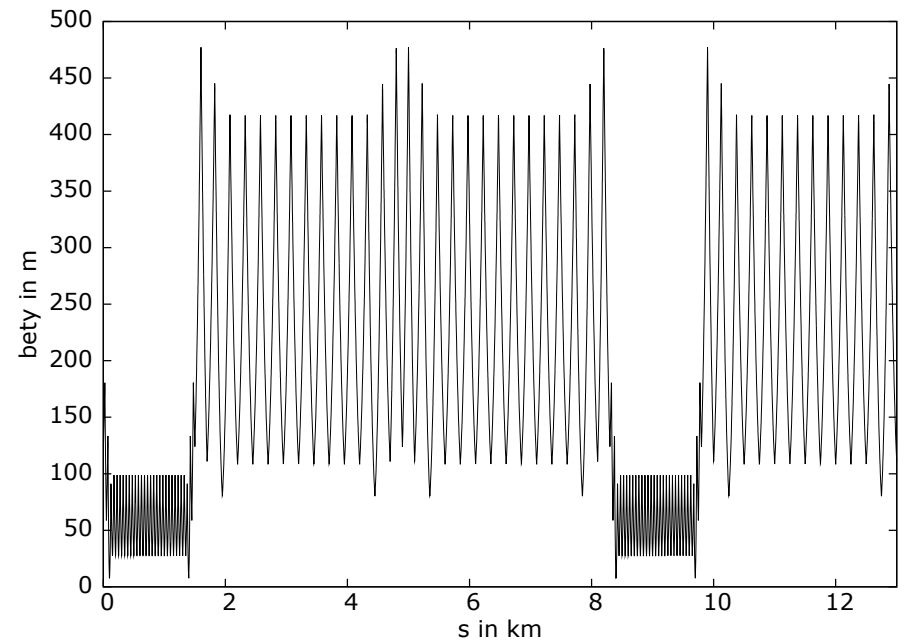
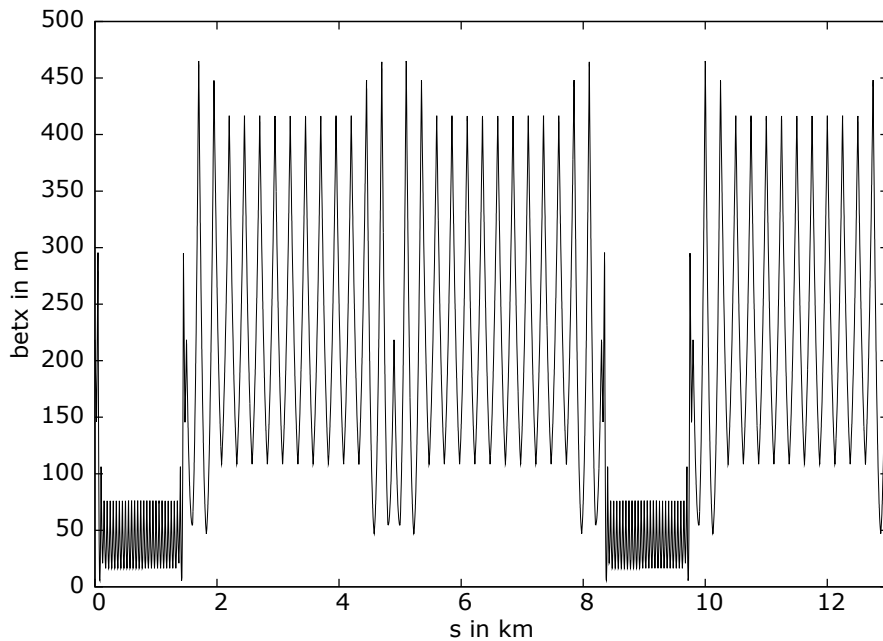
MADX Emit:

$$0.5 \times \epsilon_x = 14.6 \text{ nm}$$

$$\epsilon_x = 13.6 \text{ nm}$$

$$\epsilon_x = 12.5 \text{ nm}$$

45.5 GeV: 250 m cell length



FCC-ee baseline parameter:

Analytical calculation:

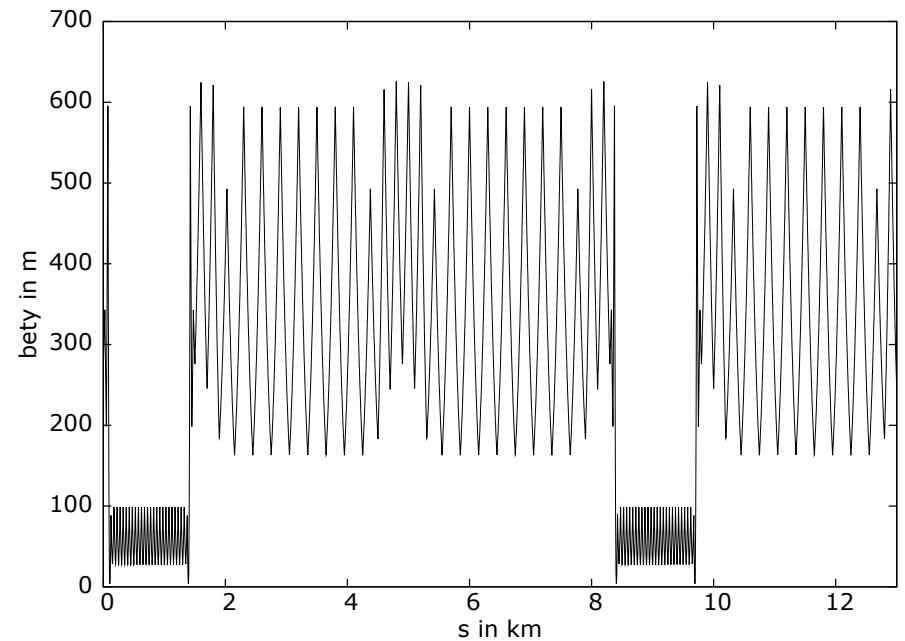
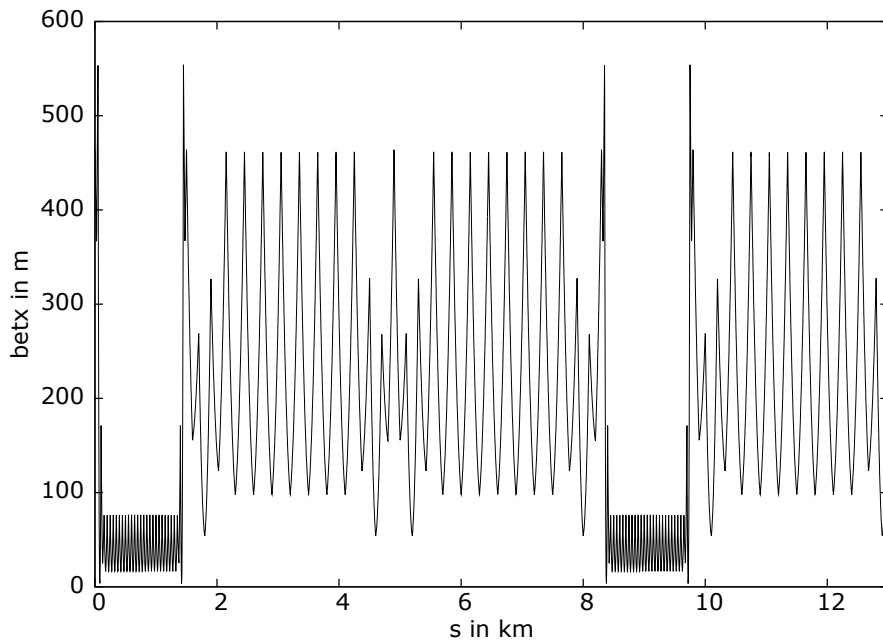
MADX Emit:

$$0.5 \times \epsilon_x = 14.6 \text{ nm}$$

$$\epsilon_x = 15.9 \text{ nm}$$

$$\epsilon_x = 14.5 \text{ nm}$$

45.5 GeV: 300 m cell length



FCC-ee baseline parameter:

Analytical calculation:

MADX Emit:

$$0.5 \times \epsilon_x = 14.6 \text{ nm}$$

$$\epsilon_x = 15.2 \text{ nm}$$

$$\epsilon_x = 14.2 \text{ nm}$$

Next steps

1. Introduction of misalignments and coupling
 - Which lattice is most stable?
 - How much does horizontal emittance increase?
 - Calculation of the distorted orbit and vertical emittance
2. Which software is reliable for those calculations?
3. State-of-the-art chromaticity correction scheme
3. Investigate light source lattices for colliders

Résumé I

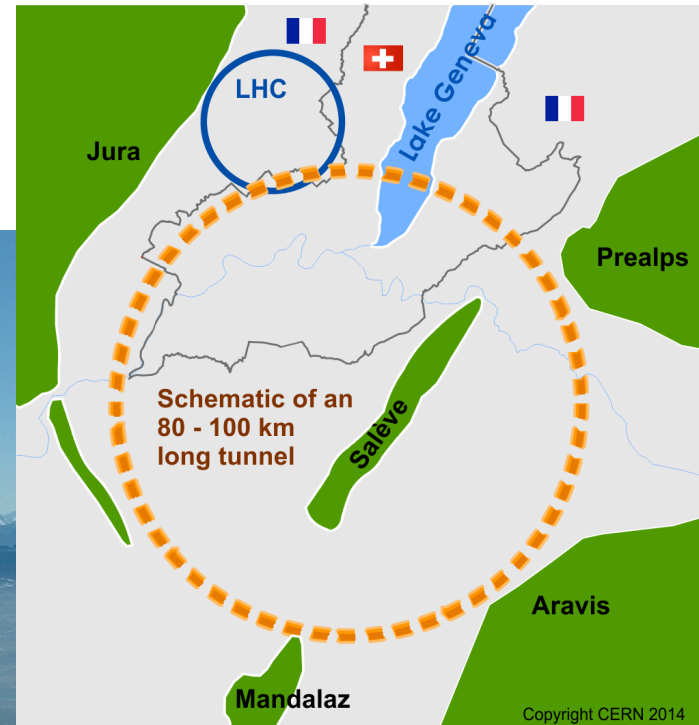
- The baseline parameter provide a variety of challenges for the lattice design
 - A lattice with highest flexibility is needed
- To achieve the emittance baseline parameters the lattice has to be modified
- Two possible alternatives:
 - Changing of the cell length
 - Changing of the phase advance

Résumé II

- Different beam optics were determined to obtain the required emittances for all 4 energies.
- For 175 GeV and 120 GeV beam energy the same lattice can be used
- For 80 GeV and 45.5 GeV several lattices with different cell length and phase advance were implemented
- This is just the very first design!
 - Misalignment studies, chromaticity correction scheme



Thank you for your attention!



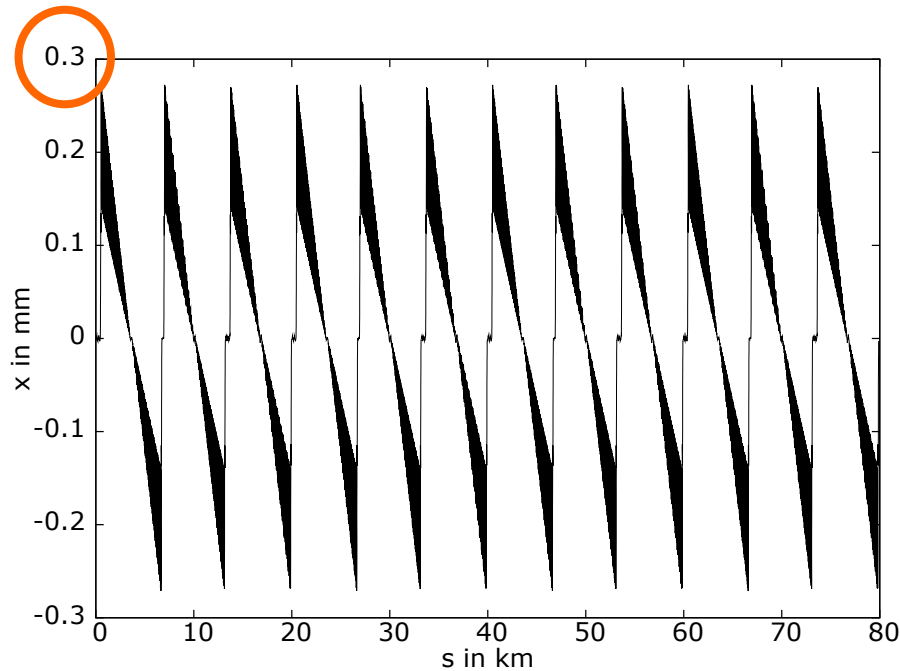
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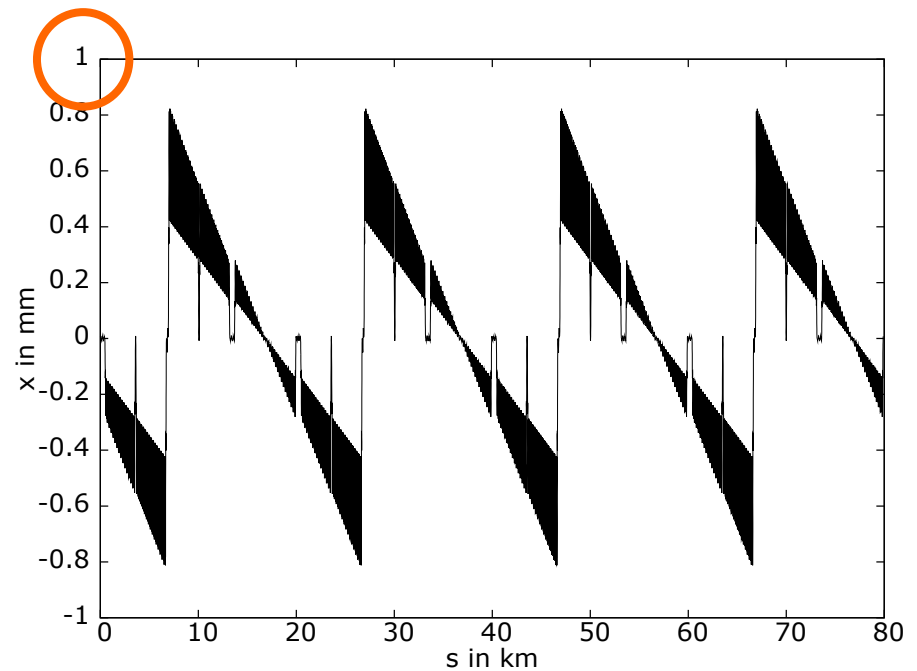
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Energy sawtooth



12 RF sections



4 RF sections

Energy loss per turn: $U_0 = 7.72$ GeV

80 GeV: important parameters

Cell length in arc (m)	50	100	Baseline
Phase advance in arc cell	45°/45°	90°/60°	parameter
Horizontal emittance (nm)	1.47	1.70	2 x 1.65
Energy loss per turn (MeV)	337.03	337.03	330
Momentum compaction (10^{-5})	1.99	2.22	2
Max. hor. beta function in arc (m)	141.47	181.54	-
Max. vert. beta function in arc (m)	141.68	211.05	-
Max. dispersion in arc (m)	0.41	0.58	-

45.5 GeV: important parameters

Cell length in arc (m)	200	250	300	Baseline
Phase advance in arc cell	60°/60°	72°/72°	90°/60°	parameter
Horizontal emittance (nm)	12.5	14.5	14.2	2 x 14.6
Energy loss per turn (MeV)	35.3	35.3	35.3	30
Momentum compaction (10^{-4})	1.69	1.86	1.81	1.8
Max. hor. beta function in arc (m)	366.51	465.71	554.00	-
Max. vert. beta function in arc (m)	407.92	477.70	626.43	-
Max. dispersion in arc (m)	4.02	4.87	4.56	-
RMS beam size σ_x in arc* (mm)	2.1	2.6	2.8	-

* $\sigma_x = \sqrt{\varepsilon_x \beta_x}$